

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-80	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-3	A
Peak Pulse Current	I _{CM}	-6	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

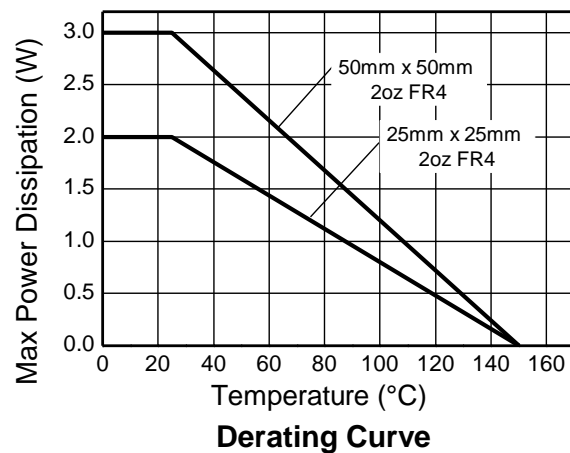
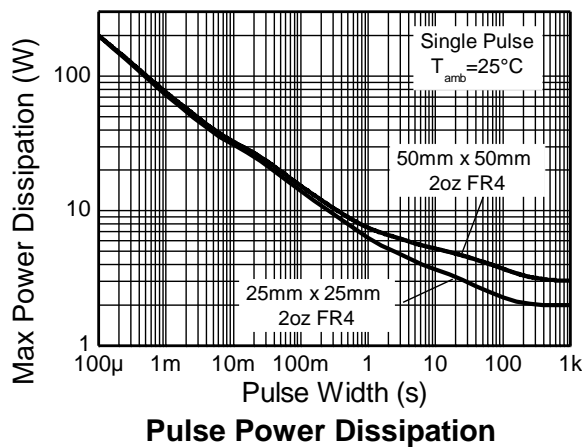
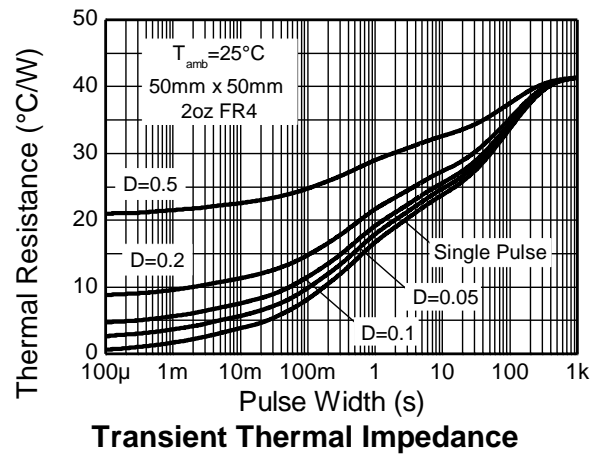
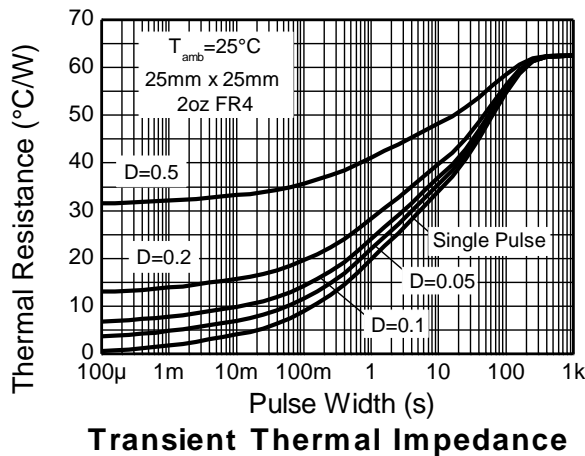
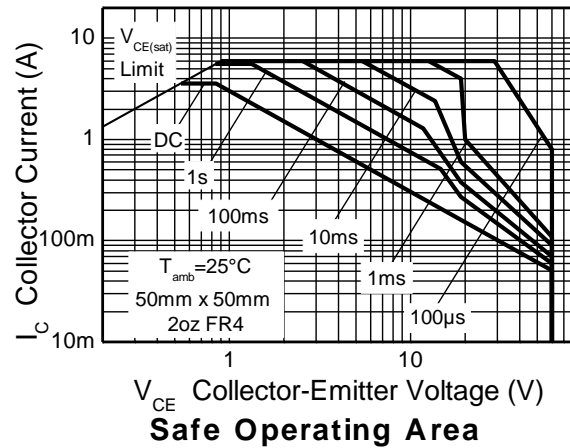
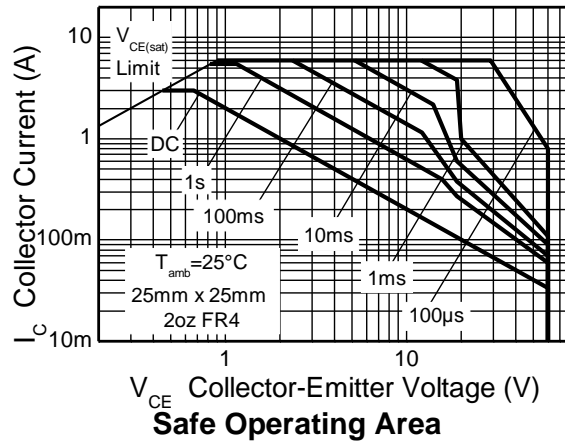
Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	2	W
		3	W
Thermal Resistance, Junction to Ambient	R _{θJA}	62.5	°C/W
		41.7	°C/W
Thermal Resistance, Junction to Leads	R _{θJL}	12.9	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
 - Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
 - Thermal resistance from junction to solder-point (at the end of the collector lead).
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

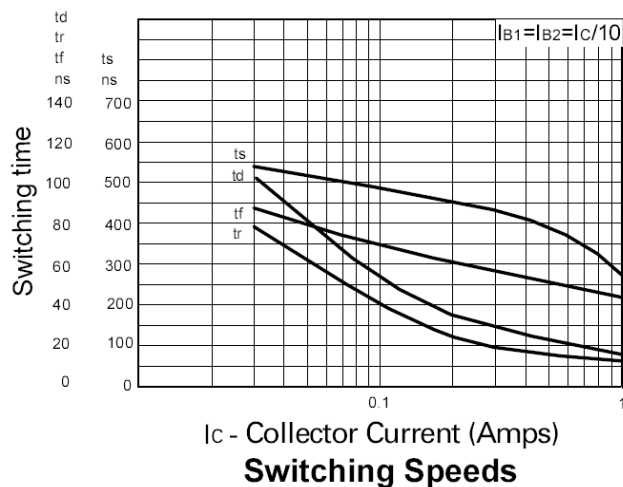
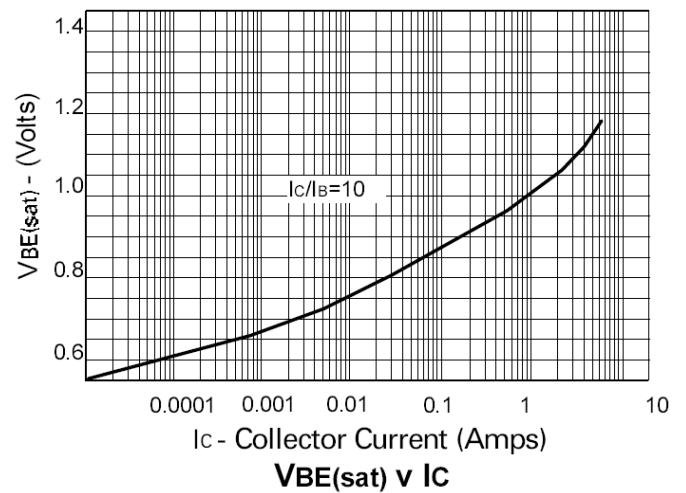
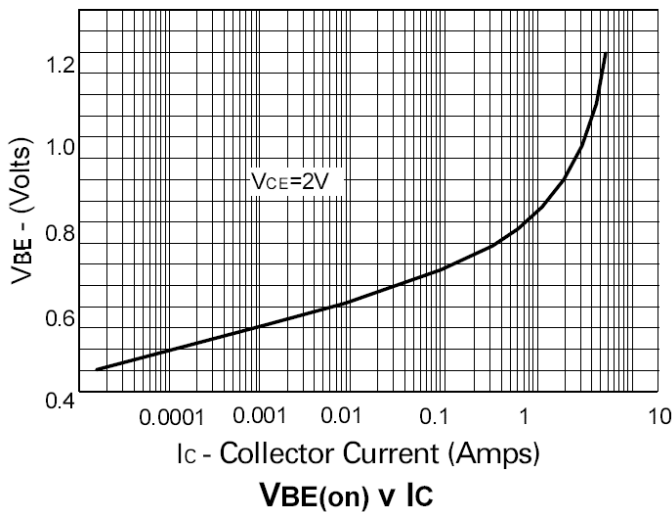
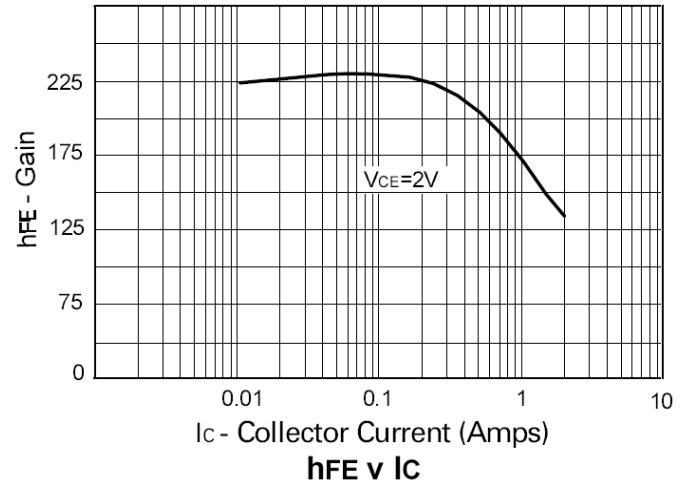
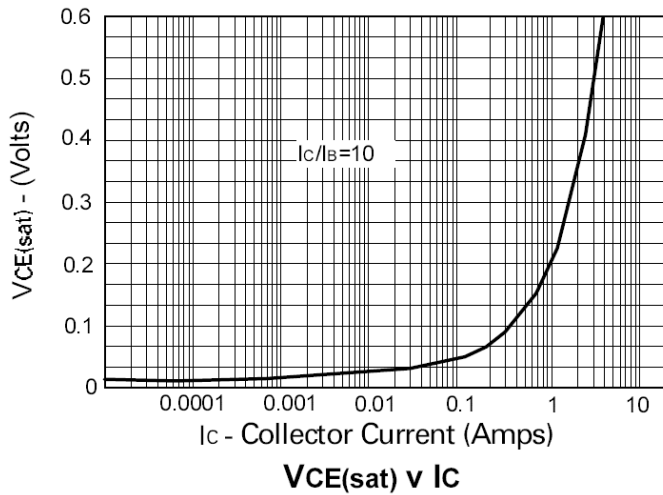


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-80	—	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-60	—	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	—	—	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	—	<1	-100	nA	V _{CB} = -60V
		—	—	-10	μA	V _{CB} = -60V, T _{amb} = +100°C
Emitter Cut-Off Current	I _{EBO}	—	<1	-100	nA	V _{EB} = -4V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	—	-0.15	-0.3	V	I _C = -1A, I _B = -100mA
		—	-0.45	-0.6		I _C = -3A, I _B = -300mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	—	-0.9	-1.25	V	I _C = -1A, I _B = -100mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	—	-0.8	-1.0	V	I _C = -1A, V _{CE} = -2V
DC Current Gain (Note 9)	h _{FE}	70	200	—	—	I _C = -50mA, V _{CE} = -2V
		100	200	300		I _C = -500mA, V _{CE} = -2V
		80	170	—		I _C = -1A, V _{CE} = -2V
		40	150	—		I _C = -2A, V _{CE} = -2V
Current Gain-Bandwidth Product	f _T	100	140	—	MHz	V _{CE} = -5V, I _C = -100mA f = 100MHz
Turn-On Time	t _{on}	—	40	—	ns	V _{CC} = -10V, I _C = -500mA
Turn-Off Time	t _{off}	—	450	—	ns	I _{B1} = I _{B2} = -50mA
Output Capacitance	C _{obo}	—	—	30	pF	V _{CB} = -10V, f = 1MHz

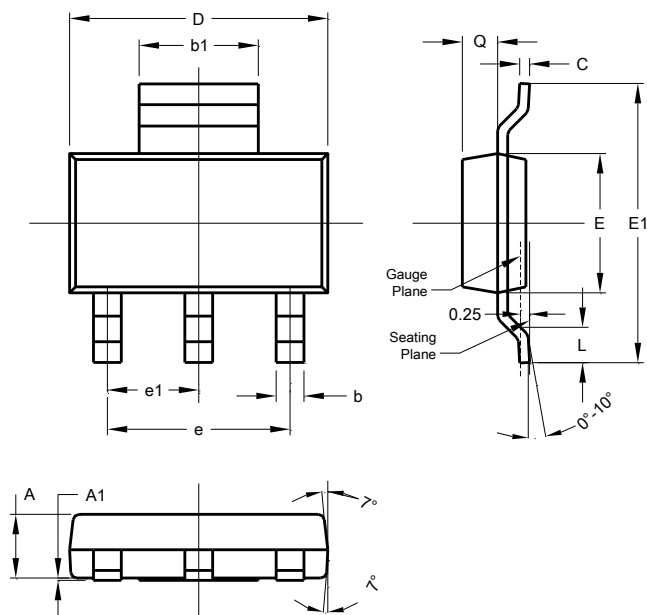
Note: 9. Measured under pulsed conditions. Pulse width ≤ 300 μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



Package Outline Dimensions

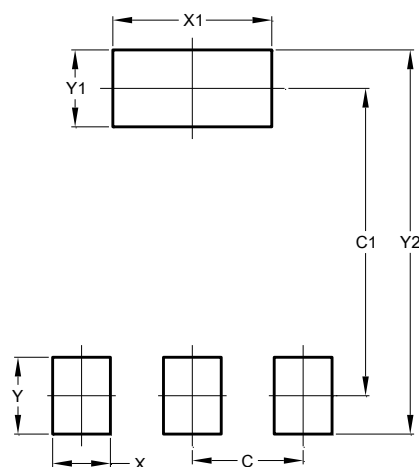
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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